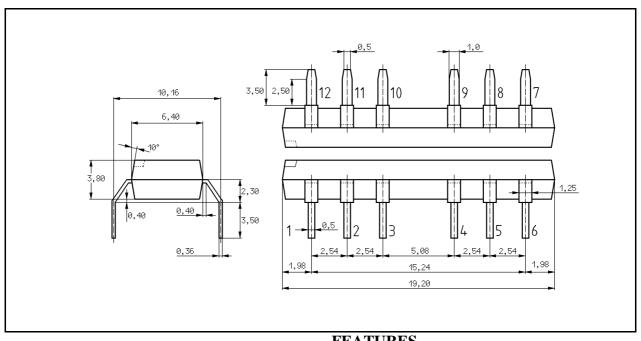
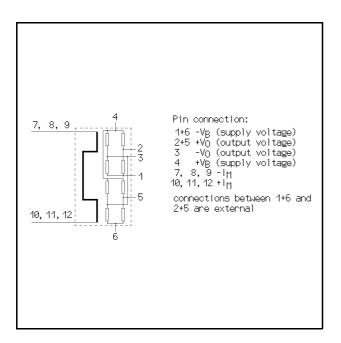


# **Current Sensor**

Issue 2 - July 2006







# **FEATURES**

- Package : mod. DIL-14 (12 pin)
- Double magnetic sensor chip (employing the magnetoresistive effect of thin film permalloy) measures the magnetic field generated by an internal current-carrying conductor
- $\bullet$  measurable direct or alternating current  $I_M$  up to 10A
- supply voltage 12 V
- no auxiliary field H<sub>X</sub> required
- it's possible to overload the conductor (between pin's 8,9,10 and 11,12,13) with 300A for 10 ms at  $T_{amb} = 25$  °C

# **ZMC 10D**

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol		Unit
Supply voltage	V <sub>br</sub>	12	V
Supply current	Ibr	20	mA
Measurable current at DC: absolute value at AC: peak value	Im	10	А
Operating temperature range	T <sub>amb</sub>	-25 to +100	°C
Storage temperature range	T <sub>stg</sub>	-25 to +125	°C

# **ELECTRICAL CHARACTERISTICS** (at T<sub>amb</sub> = 25 °C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Input-Output-Insulation (pin 7, 8, 9, 10, 11, 12 shorted together and pin 1, 2, 3, 4, 5, 6 shorted together)	I <sub>i-o</sub>	-	-	5	nA	test voltage: 2000V DC test time: 1s
Bridge resistance	R <sub>br</sub>	600	800	1300	Ω	
Temperature coefficient of bridge resistance	T <sub>crbr</sub>	-	+0.3	-	%/K	$T_{amb} = -25+100^{\circ}C$
Bridge supply current (con- stant current source)	I <sub>br</sub>	-	13	-	mA	$T_{amb} = -25+100^{\circ}C$
Offset coefficient of V <sub>outoff1</sub> (current supply rejection ratio)	CSRR	-	±1.5	±2.5	mV/mA	
Offset voltage (static, con- stant)	V <sub>outoff1</sub>	-	±19	æ32	mV	$I_{br} = 13mA$ and $R_{br} = 0.8k\Omega$
Offset voltage (dynamic, nonlinear)	Voutoff2	-	-	±2	mV	in dependence on $I_m$ and $T_{amb}$
Temperature coefficient of Voutoff1	T <sub>cvoff1</sub>	-35	-	+35	μV/K	$I_{br} = 13mA \text{ and} \\ R_{br} = 0.8k\Omega$
Open circuit sensitivity (absolute V <sub>out</sub> /I <sub>m</sub> , with off- set compensation, no dis- turbing field allowed)	Sa	2.7	3.9	5.1	mV/A	$I_{br} = 13mA \text{ and} \\ R_{br} = 0.8k\Omega$
Resistance of the conductor	R	-	0.7	-	mΩ	$I_m \le 10A$
Operating frequency	f <sub>max</sub>	0	-	100	kHz	

## **ELECTRICAL CHARACTERISTICS** (at T<sub>amb</sub> = 25 °C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Temparature coefficient of S <sub>a</sub>	T <sub>csi</sub>	-	-	-0.12	%/K	$I_{br} = 13mA \text{ and} \\ R_{br} = 0.8k\Omega$
Output voltage range	V <sub>out</sub>	-	_	<æ10 0	mV	$I_{br} = 13mA \text{ and} \\ R_{br} = 0.8k\Omega$
Nonlinearity error of Sa	NLE	-	6	_	%	$I_{m1} = 1A; I_{m2} = 2A$
Disturbance signal influence on disturbing field H <sub>d</sub> (V <sub>out</sub> =I <sub>m</sub> *S <sub>a</sub> + V <sub>outhd</sub> )	Vouthd	-	±0.5	-	mV	$I_{br} = 13m; R_{br} = 0.8k\Omega$ and $H_d = 10A/m$ in 50mm distance to sensor

### **Equations of condition:**

$V_{outoff1} [mV] = CSRR [mV/mA] * I_{br} [mA]$	
CSRR $[mV/mA] = (R_{34} + R_{12} - R_{24} - R_{13}) [\Omega]$	* 0.5 (at $I_m = 0$ )
pinning of magnetoresistive resistors:	R <sub>34</sub> : between pin 3 and pin 4
	$R_{12}$ : between pin 1 and pin 2
	R <sub>24</sub> : between pin 2 and pin 4
	R <sub>13</sub> : between pin 1 and pin 3
external connections:	pin 2 shorted to pin 5
	pin 1 shorted to pin 6

### **Circuit connections:**

condition: pin4: +Ibr and pin 1,6: -Ibr

Devices are identified by type on the body of the device:

ZMC10D ..... ZMC10D

Ordering information:

ZMC10D..... in boxes

#### Europe

Zetex GmbH Streitfeldstraße 19 D-81673 München Germany

Telefon: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 49 europe.sales@zetex.com Americas Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA

Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com

#### Asia Pacific

Zetex (Asia Ltd) 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong

Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com

#### Corporate Headquarters

Zetex Semiconductors plc Zetex Technology Park, Chadderton Oldham, OL9 9LL United Kingdom

Telephone: (44) 161 622 4444 Fax: (44) 161 622 4446 hq@zetex.com

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